Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006-3 (SOT883) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection
- AEC-Q101 qualified

3. Applications

- Relay driver
- · High-speed line driver
- · Low-side load switch
- · Switching circuits

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-------------------|----------------------------------|--|-----|-----|-----|-----|------|
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | - | 60 | V |
| V_{GS} | gate-source voltage | | | -20 | - | 20 | V |
| I _D | drain current | V _{GS} = 10 V; T _{amb} = 25 °C | [1] | - | - | 350 | mA |
| Static charac | teristics | | | | | | |
| R _{DSon} | drain-source on-state resistance | $V_{GS} = 10 \text{ V}; I_D = 100 \text{ mA}; T_j = 25 \text{ °C}$ | | - | 2.2 | 3 | Ω |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².



5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|------------------------------------|----------------|
| 1 | G | gate | | D |
| 2 | S | source | 3 | |
| 3 | D | drain | 1 2 | G |
| | | | top view DFN1006-3 (SOT883) | S 017aaa255 |

6. Ordering information

Table 3. Ordering information

| Type number Package | | | | | | |
|---------------------|------|---|---------|--|--|--|
| | Name | Description | Version | | | |
| BSS138AKM-Q | | plastic, leadless ultra small package; 3 terminals; 0.35 mm pitch; 1 mm x 0.6 mm x 0.48 mm body | SOT883 | | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| BSS138AKM-Q | BP |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|----------------------|--|---|-----|-----|------|------|
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | 60 | V |
| V _{GS} | gate-source voltage | | | -20 | 20 | V |
| I _D | drain current | V _{GS} = 10 V; T _{amb} = 25 °C | [1] | - | 350 | mA |
| | | V _{GS} = 10 V; T _{amb} = 100 °C | [1] | - | 220 | mA |
| I _{DM} | peak drain current | T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$ | | - | 2.96 | Α |
| P _{tot} | total power dissipation | T _{amb} = 25 °C | [2] | - | 350 | mW |
| | | | [1] | - | 710 | mW |
| | | T _{sp} = 25 °C | | - | 3.1 | W |
| T _j | junction temperature | | | -55 | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |
| Source-drain | n diode | | | ' | | |
| Is | source current | T _{amb} = 25 °C | [1] | - | 470 | mA |
| ESD maximu | ım rating | | | | | |
| V _{ESD} | electrostatic discharge voltage | НВМ | | - | 500 | V |
| Avalanche ru | uggedness | | | 1 | | |
| E _{DS(AL)S} | non-repetitive drain- source avalanche energy | $T_{j(init)}$ = 25 °C; I_D = 0.02 A; DUT in avalanche (unclamped) | | - | 6.8 | mJ |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

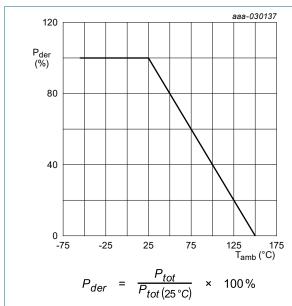


Fig. 1. Normalized total power dissipation as a function of ambient temperature

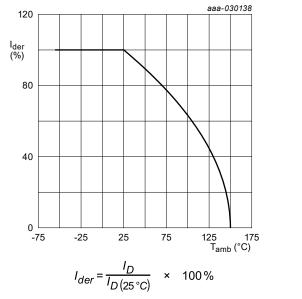


Fig. 2. Normalized continuous drain current as a function of ambient temperature

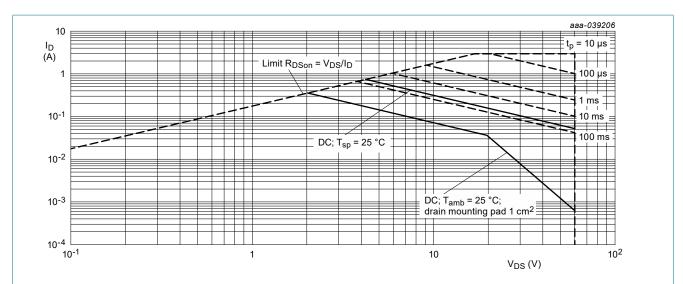


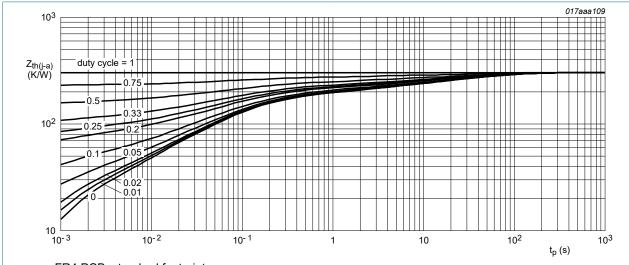
Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

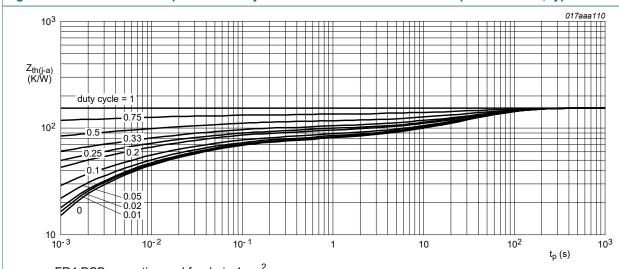
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------|--|-------------|-----|-----|-----|-----|------|
| R _{th(j-a)} | thermal resistance from | in free air | [1] | - | 305 | 360 | K/W |
| junction to ambient | junction to ambient | | [2] | - | 150 | 175 | K/W |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | | | - | 35 | 40 | K/W |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².



FR4 PCB, standard footprint

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for drain 1 cm²

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|-----------------------------------|---|-----|-------|-------|------|
| Static char | acteristics | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$ | 60 | - | - | V |
| V_{GSth} | gate-source threshold voltage | $I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$ | 0.8 | 1.1 | 1.5 | V |
| I _{DSS} | drain leakage current | V _{DS} = 60 V; V _{GS} = 0 V; T _j = 25 °C | - | - | 1 | μΑ |
| I _{GSS} | gate leakage current | V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C | - | - | 10 | μΑ |
| | | V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C | - | - | -10 | μΑ |
| | | V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C | - | - | 1 | μΑ |
| | | $V_{GS} = -10 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$ | - | - | -1 | μΑ |
| | | V _{GS} = 4.5 V; V _{DS} = 0 V; T _j = 25 °C | - | - | 500 | nA |
| | | V _{GS} = -4.5 V; V _{DS} = 0 V; T _j = 25 °C | - | - | -500 | nA |
| Doon | drain-source on-state | V_{GS} = 10 V; I_D = 100 mA; T_j = 25 °C | - | 2.2 | 3 | Ω |
| | resistance | V _{GS} = 10 V; I _D = 100 mA; T _j = 150 °C | - | 4.2 | 5.7 | Ω |
| | | $V_{GS} = 4.5 \text{ V}; I_D = 50 \text{ mA}; T_j = 25 ^{\circ}\text{C}$ | - | 2.7 | 3.9 | Ω |
| | | V_{GS} = 2.5 V; I_D = 10 mA; T_j = 25 °C | - | 3.4 | 12 | Ω |
| 9 _{fs} | forward transconductance | $V_{DS} = 5 \text{ V}; I_D = 100 \text{ mA}; T_j = 25 \text{ °C}$ | - | 0.4 | - | S |
| Dynamic c | haracteristics | | | | - | |
| Q _{G(tot)} | total gate charge | V _{DS} = 30 V; I _D = 100 mA; V _{GS} = 10 V; | - | 0.21 | 0.315 | nC |
| Q _{GS} | gate-source charge | T _j = 25 °C | - | 0.022 | - | nC |
| Q _{GD} | gate-drain charge | | - | 0.051 | - | nC |
| C _{iss} | input capacitance | V _{DS} = 30 V; f = 1 MHz; V _{GS} = 0 V; | - | 9 | - | pF |
| C _{oss} | output capacitance | T _j = 25 °C | - | 1.8 | - | pF |
| C _{rss} | reverse transfer capacitance | | - | 1.1 | - | pF |
| t _{d(on)} | turn-on delay time | V _{DS} = 30 V; I _D = 100 mA; V _{GS} = 10 V; | - | 1 | - | ns |
| t _r | rise time | $R_{G(ext)} = 6 \Omega; T_j = 25 °C$ | - | 1 | - | ns |
| t _{d(off)} | turn-off delay time | 7 | - | 2 | - | ns |
| t _f | fall time | | - | 3 | - | ns |
| Source-dra | ain diode | | ' | ' | | |
| V _{SD} | source-drain voltage | I _S = 470 mA; V _{GS} = 0 V; T _j = 25 °C | - | 0.98 | 1.7 | V |
| t _{rr} | reverse recovery time | $I_S = 500 \text{ mA}; dI_S/dt = -100 \text{ A/}\mu\text{s};$ | - | 7 | - | ns |
| Q _r | recovered charge | $V_{GS} = 0 \text{ V}; V_{DS} = 30 \text{ V}; T_i = 25 \text{ °C}$ | | 1 | | nC |

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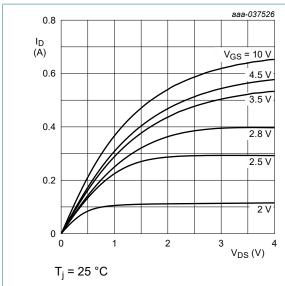


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

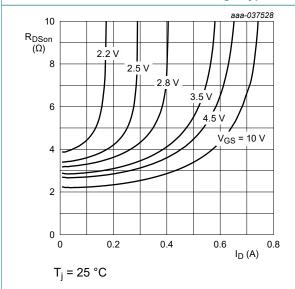


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

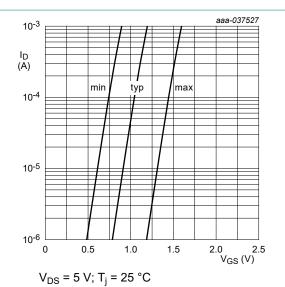


Fig. 7. Sub-threshold drain current as a function of gate-source voltage

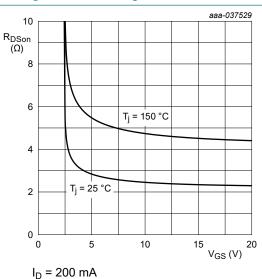


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

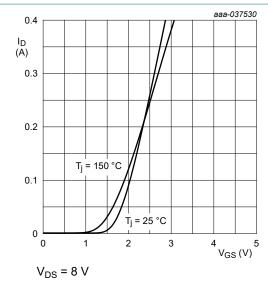


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

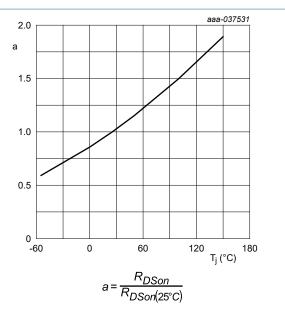


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

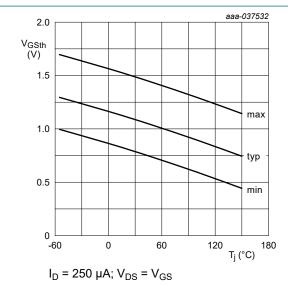


Fig. 12. Gate-source threshold voltage as a function of junction temperature

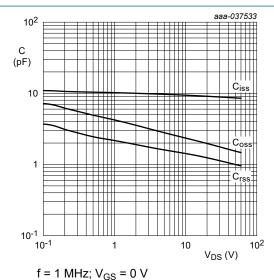


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

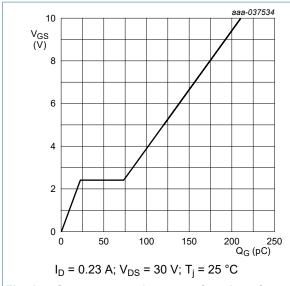


Fig. 14. Gate-source voltage as a function of gate charge; typical values

 $V_{GS} = 0 V$

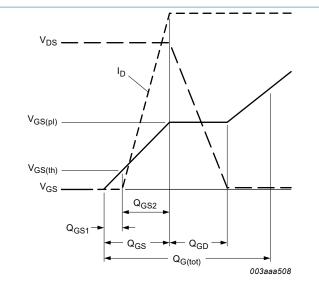


Fig. 15. Gate charge waveform definitions

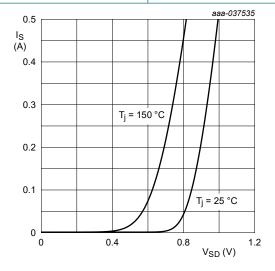
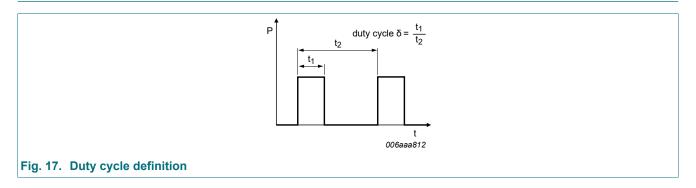


Fig. 16. Source current as a function of source-drain voltage; typical values

11. Test information



Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

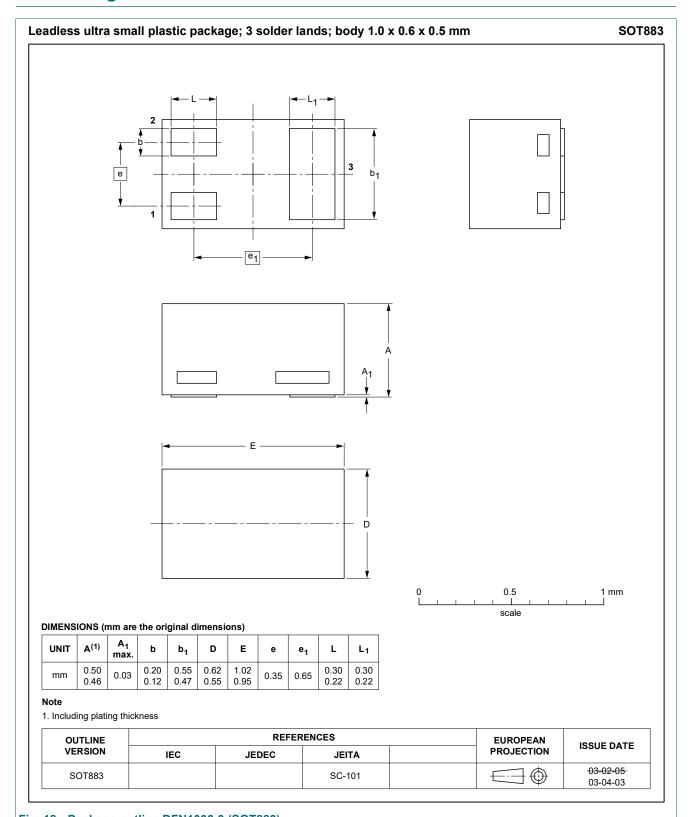
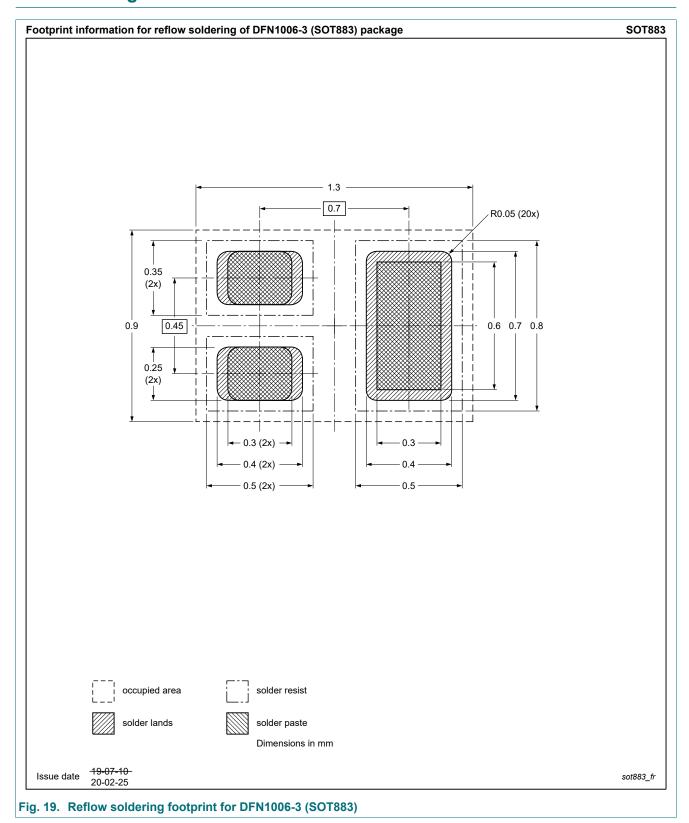


Fig. 18. Package outline DFN1006-3 (SOT883)

13. Soldering



14. Revision history

Table 8. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
|-----------------|--------------|--------------------|---------------|------------|
| BSS138AKM-Q v.1 | 20240402 | Product data sheet | - | - |

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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